SN55LVCP22 QML Class Q 2×2 1-Gbps LVDS Crosspoint Switch

1 Features

- QML class Q, SMD 5962-11242
- High-speed (up to 1000 Mbps)
- Low-jitter fully differential data path
- 50 ps (typ), of peak-to-peak jitter with PRBS = 2^{23}–1 pattern
- Less than 227 mW (typ), 313 mW (max) total power dissipation
- Output (channel-to-channel) skew is 80 ps (typ)
- Configurable as 2:1 mux, 1:2 demux, repeater or 1:2 signal splitter
- Inputs accept LVDS, LVPECL, and CML signals
- Fast switch time of 1.7 ns (typ)
- Fast propagation delay of 0.65 ns (typ)
- Inter-operates with TIA/EIA-644-A LVDS standard
- Supports defense, aerospace, and medical applications:
  - Controlled baseline
  - One assembly/test site and one fabrication site
  - Extended product life cycle and extended product-change notification
  - Product traceability

2 Applications

- Global positioning system receiver
- Defense radio
- Sonar
- Seeker front end
- Radar

3 Description

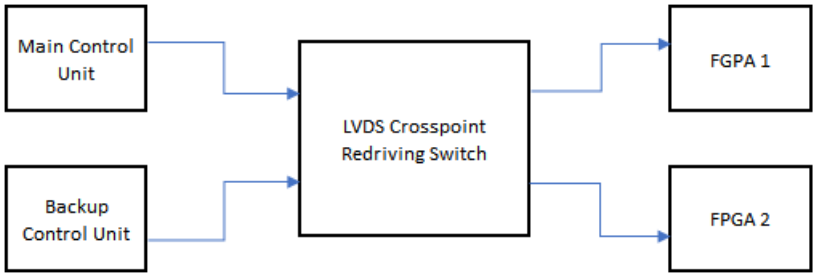
The SN55LVCP22 is a 2×2 crosspoint switch providing greater than 1000 Mbps operation for each path. The dual channels incorporate wide common-mode (0 V to 4 V) receivers, allowing for the receipt of LVDS, LVPECL, and CML signals. The dual outputs are LVDS drivers to provide low-power, low-EMI, high-speed operation. The SN55LVCP22 provides a single device supporting 2:2 buffering (repeating), 1:2 splitting, 2:1 multiplexing, 2×2 switching, and LVPECL/CML to LVDS level translation on each channel. The flexible operation of the SN55LVCP22 provides a single device to support the redundant serial bus transmission needs (working and protection switching cards) of fault-tolerant switch systems found in optical networking, wireless infrastructure, and data communications systems.

The SN55LVCP22 uses a fully differential data path to ensure low-noise generation, fast switching times, low pulse width distortion, and low jitter. Output channel-to- channel skew is 80 ps (typ) to ensure accurate alignment of outputs in all applications.

Device Information

PART NUMBER	GRADE	PACKAGE(1)	BODY SIZE (NOM)
5962-112420 1QFA	QMLQ	CFP (16)	6.73 mm x 10.3 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.



Simplified Application

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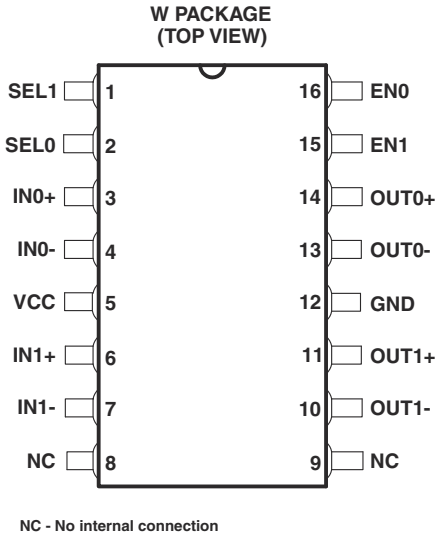
4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES
September 2020	*	Initial Release

5 Pin Configuration and Functions



Pin Functions

TERMINAL		I/O	DESCRIPTION
NAME	NO.		
SEL1	1	Input	Switch Selection Control 1
SEL0	2	Input	Switch Selection Control 2
IN0+	3	Input	LVDS Receiver Positive Input 0
IN0-	4	Input	LVDS Receiver Negative Input 0
VCC	5	Power	3.3V Supply Voltage
IN1+	6	Input	LVDS Receiver Positive Input 1
IN1-	7	Input	LVDS Receiver Negative Input 1
NC	8	N/A	No Internal Connection
NC	9	N/A	No Internal Connection
OUT1-	10	Output	LVDS Driver Negative Output 1
OUT1+	11	Output	LVDS Driver Positive Output 1
GND	12	Ground	Ground
OUT0-	13	Output	LVDS Driver Negative Output 0
OUT0+	14	Output	LVDS Driver Positive Output 0
EN1	15	Input	Output Enable for Driver 1
EN0	16	Input	Output Enable for Driver 0

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range unless otherwise noted(1)

	UNIT
Supply voltage(2), V_{CC}	–0.5 V to 4 V
CMOS/TTL input voltage (ENO, EN1, SEL0, SEL1)	–0.5 V to 4 V
LVDS receiver input voltage (IN+, IN–)	–0.7 V to 4.3 V
LVDS driver output voltage (OUT+, OUT–)	–0.5 V to 4 V
LVDS output short circuit current	Continuous
Maximum Junction temperature	150°C

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values, except differential I/O bus voltages, are with respect to network ground terminals.

6.2 Handling Ratings

			MIN	MAX	UNIT
T_{stg}	Storage temperature range		-65	125	°C
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins(1)	-5000	5000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins(2)	-500	500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}	3	3.3	3.6	V
Receiver input voltage	0		4	V
Operating case (top) temperature, T_C (1)	–55		125	°C
Magnitude of differential input voltage, $\|V_{ID}\|$	0.1		3	V

(1) Maximum case temperature operation is allowed as long as the device maximum junction temperature is not exceeded.

6.4 Thermal Information

THERMAL METRIC(1)		SN55LVCP22A-SP W (CFP) 16 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	118.1	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	51.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	107.2	°C/W
ψ_{JT}	Junction-to-top characterization parameter	28.4	°C/W
ψ_{JB}	Junction-to-board characterization parameter	95.1	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.5 Electrical Characteristics

over recommended operating conditions unless otherwise noted

PARAMETER		TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
CMOS/TTL DC SPECIFICATIONS (EN0, EN1, SEL0, SEL1)						
V_{IH}	High-level input voltage		2	1.5	V_{CC}	V

over recommended operating conditions unless otherwise noted

PARAMETER		TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
V_{IL}	Low-level input voltage		GND	1.5	0.8	V
I_{IH}	High-level input current	V_{IN} = 3.6 V or 2.0 V, V_{CC} = 3.6 V	-25	±3	25	µA
I_{IL}	Low-level input current	V_{IN} = 0.0 V or 0.8 V, V_{CC} = 3.6 V	-15	±1	15	µA
V_{CL}	Input clamp voltage	I_{CL} = –18 mA		-0.8	-1.5	V
LVDS OUTPUT SPECIFICATIONS (OUT0, OUT1)						
$\|V_{OD}\|$	Differential output voltage	R_L = 75 Ω, See Figure 7-3	255	390	475	mV
		R_L = 75 Ω, V_{CC} = 3.3 V, T_A = 25°C, See Figure 7-3	320	390	430	
$\Delta\|V_{OD}\|$	Change in differential output voltage magnitude between logic states	V_{ID} = ±100 mV, See Figure 7-3	–25		25	mV
V_{OS}	Steady-state offset voltage	See Figure 7-4	1	1.2	1.45	V
ΔV_{OS}	Change in steady-state offset voltage between logic states	See Figure 7-4	–25		25	mV
$V_{OC(PP)}$	Peak-to-peak common-mode output voltage	See Figure 7-4		50		mV
I_{OZ}	High-impedance output current	V_{OUT} = GND or V_{CC}	-15		15	µA
I_{OFF}	Power-off leakage current	V_{CC} = 0 V, 1.5 V; V_{OUT} = 3.6 V or GND	-15		15	µA
I_{OS}	Output short-circuit current	V_{OUT+} or V_{OUT-} = 0 V			-8	mA
I_{OSB}	Both outputs short-circuit current	V_{OUT+} and V_{OUT-} = 0 V	–8		8	mA
C_O	Differential output capacitance	V_I = 0.4 sin(4E6πt) + 0.5 V		3		pF
LVDS RECEIVER DC SPECIFICATIONS (IN0, IN1)						
V_{TH}	Positive-going differential input voltage threshold	See Figure 7-2 and Table 7-1			100	mV
V_{TL}	Negative-going differential input voltage threshold	See Figure 7-2 and Table 7-1	–100			mV
$V_{ID(HYS)}$	Differential input voltage hysteresis			20	150	mV
V_{CMR}	Common-mode voltage range	V_{ID} = 100 mV, V_{CC} = 3.0 V to 3.6 V	0.05		3.95	V
I_{IN}	Input current	V_{IN} = 4 V, V_{CC} = 3.6 V or 0.0	-18	±1	18	µA
		V_{IN} = 0 V, V_{CC} = 3.6V or 0.0	-18	±1	18	
C_{IN}	Differential input capacitance	V_I = 0.4 sin (4E6πt) + 0.5 V		3		pF
SUPPLY CURRENT						
I_{CCQ}	Quiescent supply current	R_L = 75 Ω, EN0=EN1=High		60	87	mA
I_{CCD}	Total supply current	R_L = 75 Ω, C_L = 5 pF, 500 MHz (1000 Mbps), EN0=EN1=High		63	87	mA
I_{CCZ}	3-state supply current	EN0 = EN1 = Low		25	35	mA

(1) All typical values are at 25°C and with a 3.3-V supply.

6.6 Switching Characteristics

over recommended operating conditions unless otherwise noted

parameter		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{SET}	Input to SEL setup time	See Figure 7-7		0.8	2.2	ns
t_{HOLD}	Input to SEL hold time	See Figure 7-7		1.0	2.2	ns
t_{SWITCH}	SEL to switched output	See Figure 7-7		1.7	2.6	ns
t_{PHZ}	Disable time, high-level-to-high-impedance	See Figure 7-6		2	8	ns
t_{PLZ}	Disable time, low-level-to-high-impedance	See Figure 7-6		2	8	ns
t_{PZH}	Enable time, high-impedance -to-high-level output	See Figure 7-6		2	8	ns
t_{PZL}	Enable time, high-impedance-to-low-level output	See Figure 7-6		2	8	ns
t_{LHT}	Differential output signal rise time (20%-80%)(1)	C_L = 5 pF, See Figure 7-5		280	620	ps
t_{HLT}	Differential output signal fall time (20%-80%)(1)	C_L = 5 pF, See Figure 7-5		280	620	ps
t_{JIT}	Added peak-to-peak jitter(3)	V_{ID} = 200 mV, 50% duty cycle, V_{CM} = 1.2 V, 50 MHz, C_L = 5 pF		13.7	22.2	ps
		V_{ID} = 200 mV, 50% duty cycle, V_{CM} = 1.2 V, 240 MHz, C_L = 5 pF		13.4	24.5	
		V_{ID} = 200 mV, 50% duty cycle, V_{CM} = 1.2 V, 500 MHz, C_L = 5 pF		14.4	35.7	
		V_{ID} = 200 mV, PRBS = 2^{15}-1 data pattern, V_{CM} = 1.2 V, 240 Mbps, C_L = 5 pF		68.3	204	ps
		V_{ID} = 200 mV, PRBS = 2^{15}-1 data pattern, V_{CM} = 1.2 V, 1000 Mbps, C_L = 5 pF		73.2	282	
t_{Jrms}	Added random jitter (rms)(3)	V_{ID} = 200 mV, 50% duty cycle, V_{CM} = 1.2 V, 50 MHz, C_L = 5 pF		0.97	1.5	ps_{RMS}
		V_{ID} = 200 mV, 50% duty cycle, V_{CM} = 1.2 V, 240 MHz, C_L = 5 pF		0.85	1.53	
		V_{ID} = 200 mV, 50% duty cycle, V_{CM} = 1.2 V, 500 MHz, C_L = 5 pF		0.86	1.79	
t_{PLHD}	Propagation delay time, low-to-high-level output(1)		200	650	2350	ps
t_{PHLD}	Propagation delay time, high-to-low-level output(1)		200	650	2350	ps
t_{skew} (5)	Pulse skew ($\lvert t_{PLHD} - t_{PHLD} \rvert$)(2)	C_L = 5 pF, See Figure 7-5		45	160	ps
t_{CCS}	Output channel-to-channel skew, splitter mode	C_L = 5 pF, See Figure 7-5		80		ps
f_{MAX} (5)	Maximum operating frequency(4)		1			GHz

(1) Input: V_{IC} = 1.2 V, V_{ID} = 200 mV, 50% duty cycle, 1 MHz, t_r/t_f = 500 ps

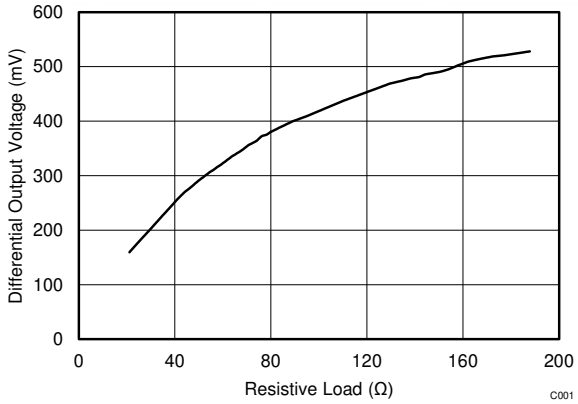
(2) t_{skew} is the magnitude of the time difference between the t_{PLHD} and t_{PHLD} of any output of a single device.

(3) Not production tested.

(4) Signal generator conditions: 50% duty cycle, t_r or $t_f \leq$ 100 ps (10% to 90%), transmitter output criteria: duty cycle = 45% to 55% $V_{OD} \geq$ 300 mV.

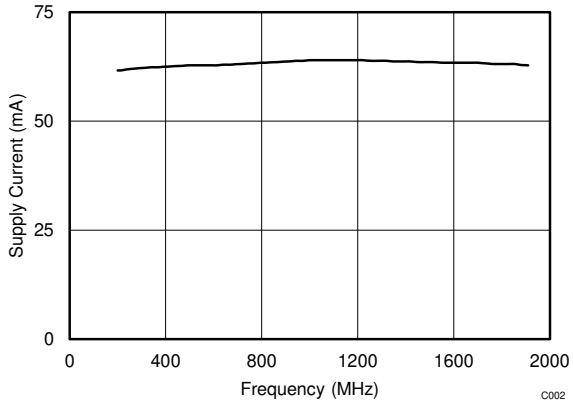
(5) t_{skew} and f_{MAX} parameters are guaranteed by characterization, but not production tested.

6.7 Typical Characteristics



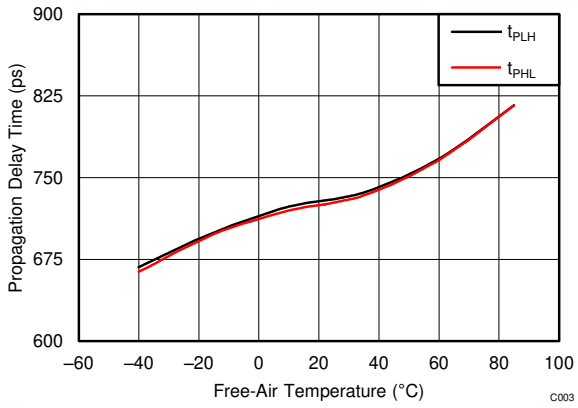
V_{CC} = 3.3 V T_A = 25°C

Figure 6-1. Differential Output Voltage vs Resistive Load



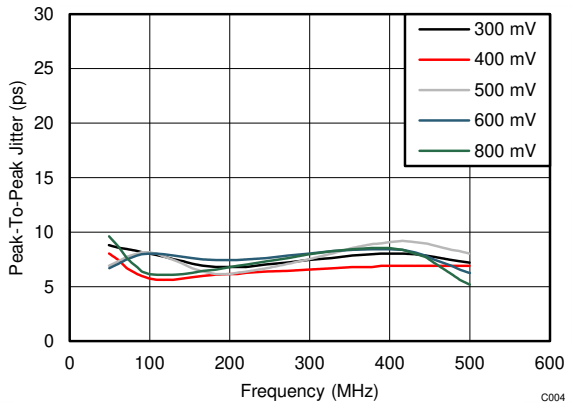
V_{CC} = 3.3 V T_A = 25°C V_{IC} = 1.2 V
$|V_{ID}|$ = 200 mV

Figure 6-2. Supply Current vs Frequency



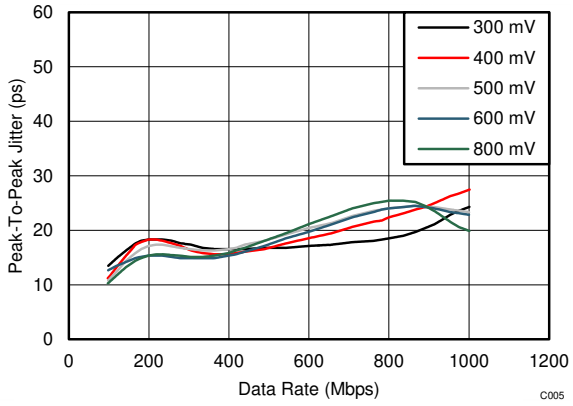
V_{CC} = 3 V - 3.6 V V_{IC} = 1.2 V $|V_{ID}|$ = 300 mV
Input = 1 MHz

Figure 6-3. Propagation Delay Time bs Ffree-Air Temperature



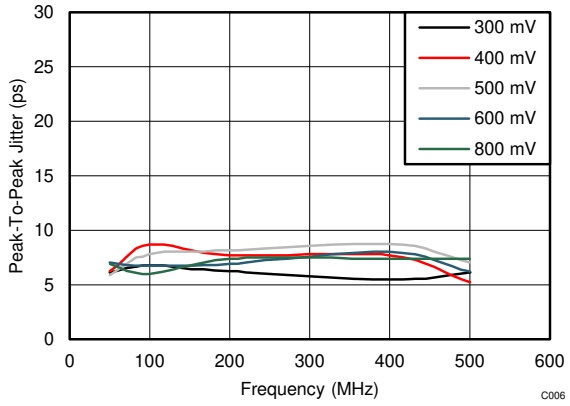
V_{CC} = 3.3 V T_A = 25°C V_{IC} = 400 mV
Input = Clock

Figure 6-4. Peak-To-Peak Jitter vs Frequency



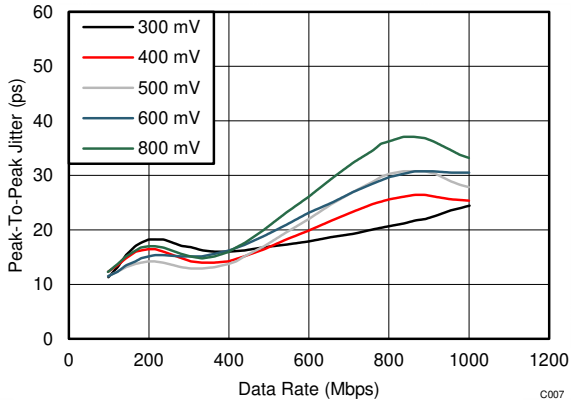
V_{CC} = 3.3 V T_A = 25°C V_{IC} = 400 mV
Input = PRBS 2^{23} –1

Figure 6-5. Peak-To-Peak Jitter vs Data Rate



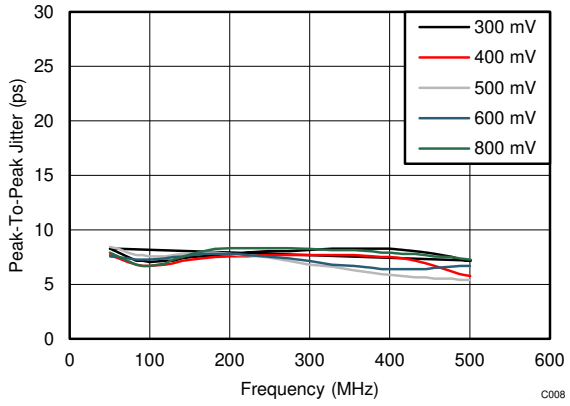
V_{CC} = 3.3 V T_A = 25°C V_{IC} = 1.2 V
Input = Clock

Figure 6-6. Peak-To-Peak Jitter vs Frequency



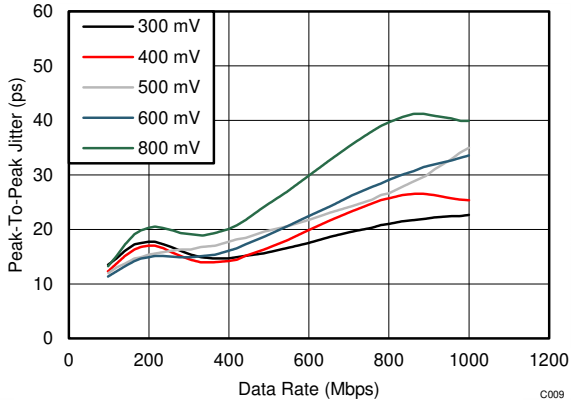
V_{CC} = 3.3 V T_A = 25°C V_{IC} = 1.2 V
Input = PRBS 2^{23} –1

Figure 6-7. Peak-To-Peak Jitter vs Data Rate



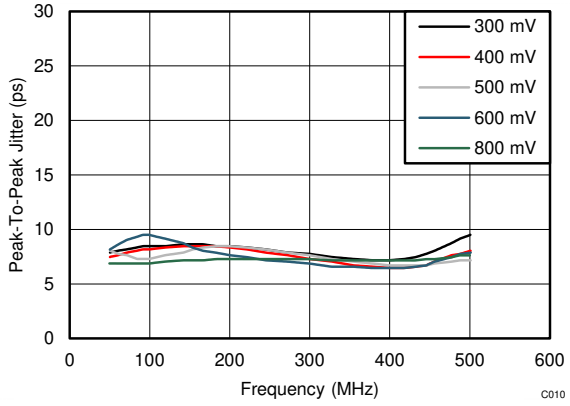
V_{CC} = 3.3 V T_A = 25°C V_{IC} = 1.6 V
Input = Clock

Figure 6-8. Peak-To-Peak Jitter vs Frequency



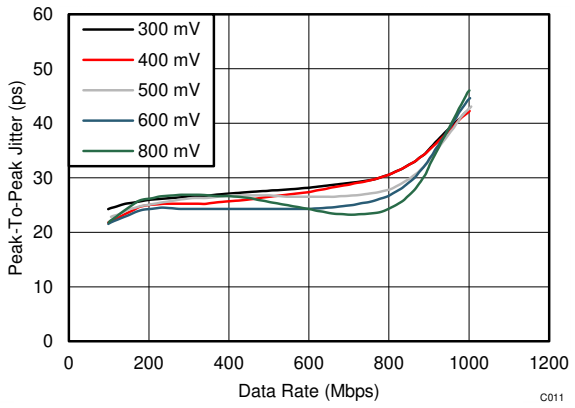
V_{CC} = 3.3 V T_A = 25°C V_{IC} = 1.6 V
Input = PRBS 2^{23} –1

Figure 6-9. Peak-To-Peak Jitter vs Data Rate



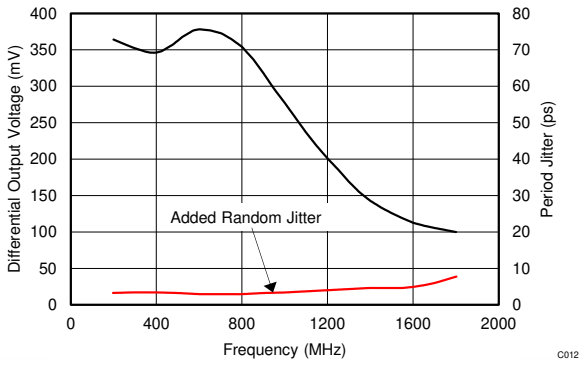
V_{CC} = 3.3 V T_A = 25°C V_{IC} = 3.3 V
Input = Clock

Figure 6-10. Peak-To-Peak Jitter vs Frequency



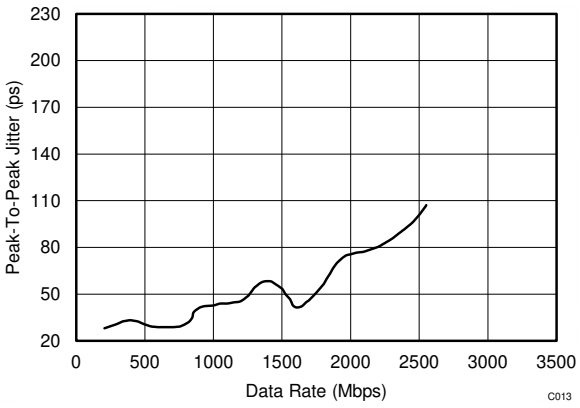
V_{CC} = 3.3 V T_A = 25°C V_{IC} = 3.3 V
Input = PRBS 2^{23} −1

Figure 6-11. Peak-To-Peak Jitter vs Data Rate



V_{CC} = 3.3 V T_A = 25°C V_{IC} = 1.2 V
$|V_{ID}|$ = 200 mV

Figure 6-12. Differential Output Voltage vs Frequency



V_{CC} = 3.3 V T_A = 25°C V_{IC} = 1.2 V
$|V_{ID}|$ = 200 mV Input = PRBS 2^{23} −1

Figure 6-13. Peak-To-Peak Jitter vs Data Rate

7 Parameter Measurement Information

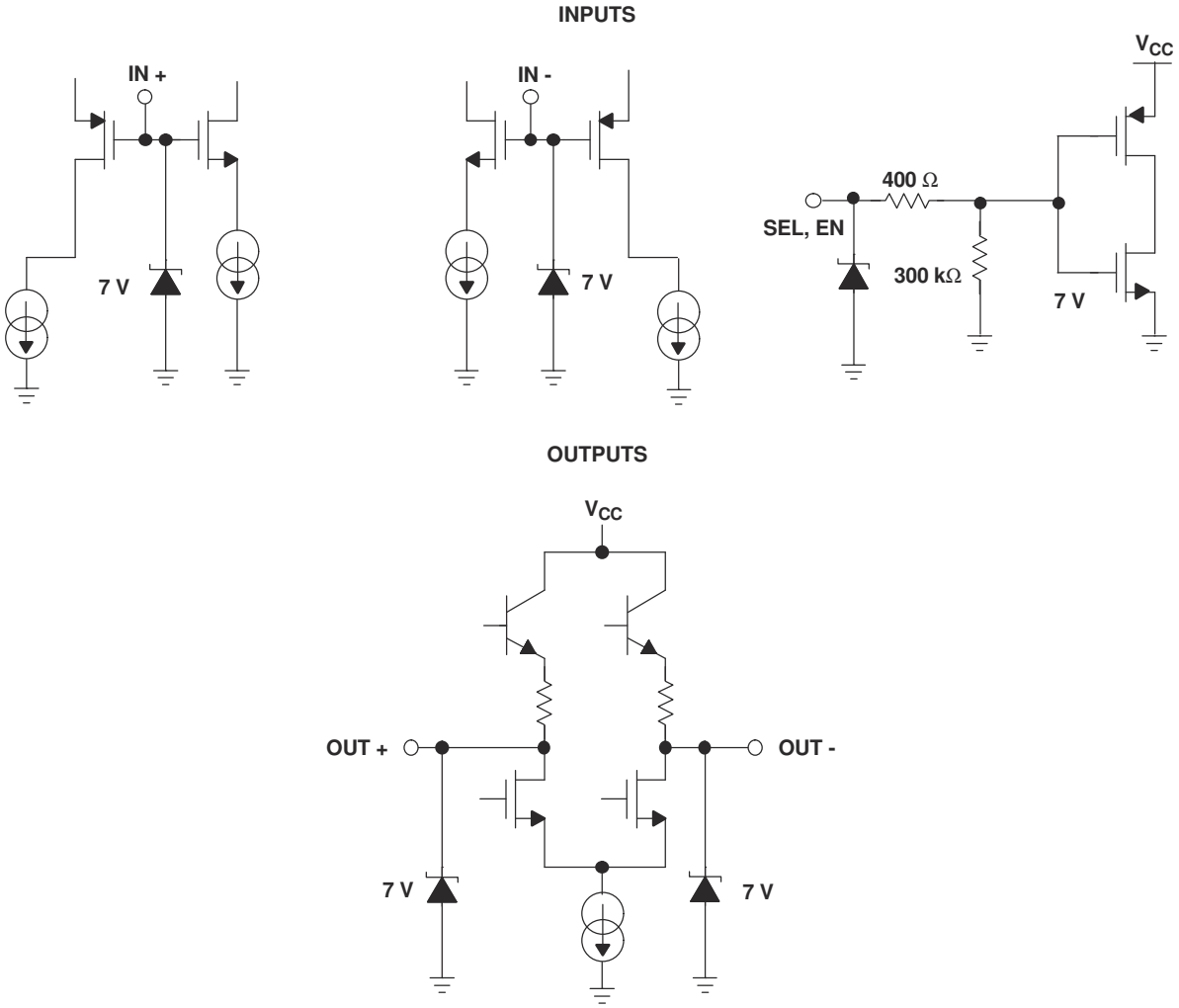


Figure 7-1. Equivalent Input and Output Schematic Diagrams

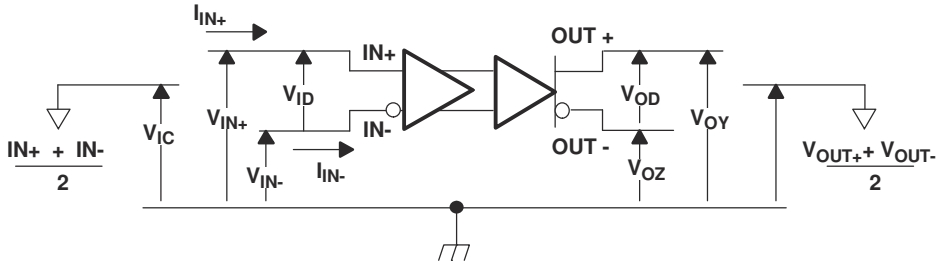


Figure 7-2. Voltage And Current Definitions

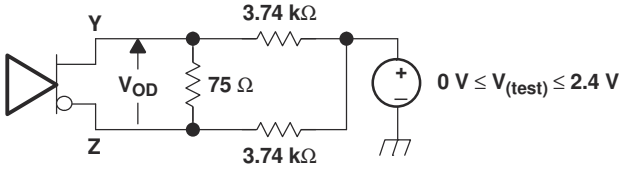
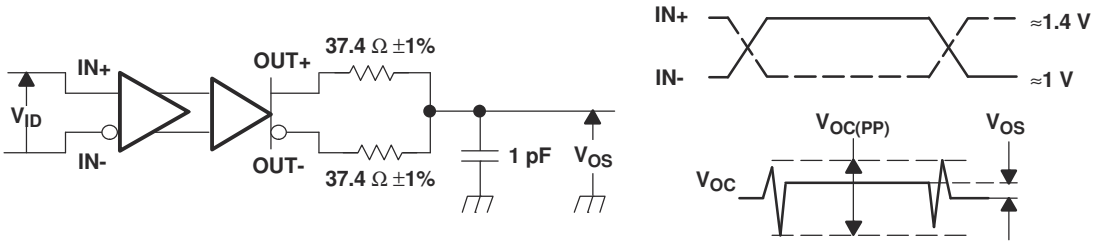
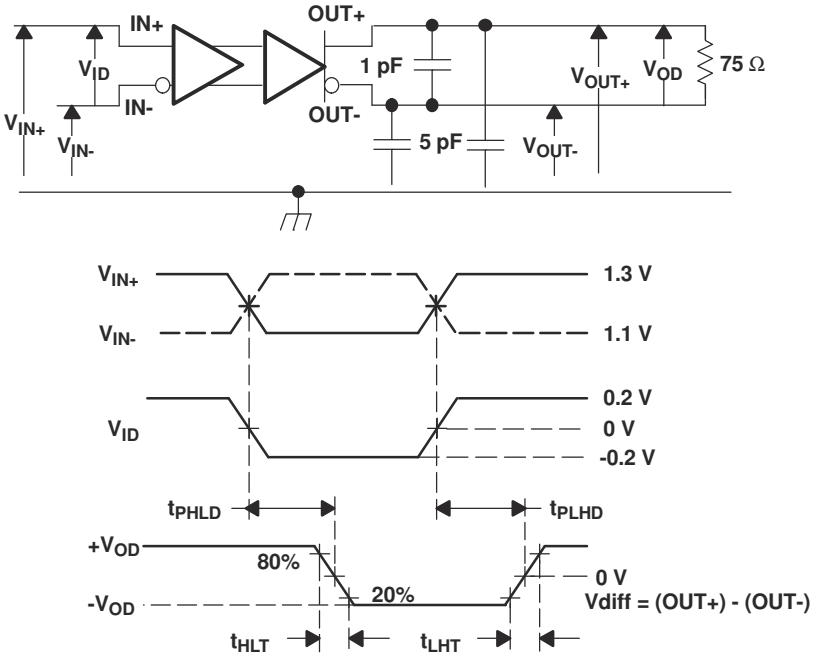


Figure 7-3. Differential Output Voltage (V_{OD}) Test Circuit



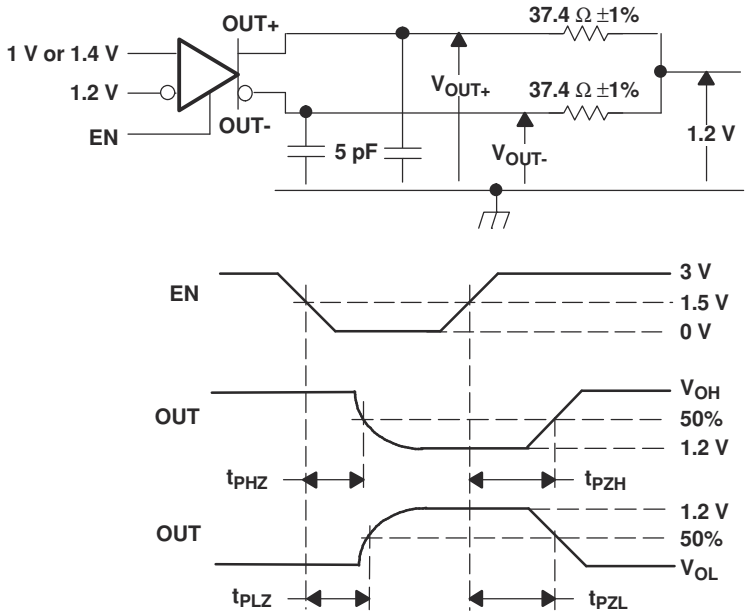
All input pulses are supplied by a generator having the following characteristics: t_r or t_f ≤ 1 ns, pulse-repetition rate (PRR) = 0.5 Mpps, pulse width = 500 ±10 ns; R_L = 100 Ω; C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.; the measurement of $V_{OC(PP)}$ is made on test equipment with a –3 dB bandwidth of at least 300 MHz.

Figure 7-4. Test Circuit And Definitions For The Driver Common-Mode Output Voltage



All input pulses are supplied by a generator having the following characteristics: t_r or t_f ≤ .25 ns, pulse-repetition rate (PRR) = 0.5 Mpps, pulse width = 500 ± 10 ns. C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.

Figure 7-5. Timing Test Circuit And Waveforms



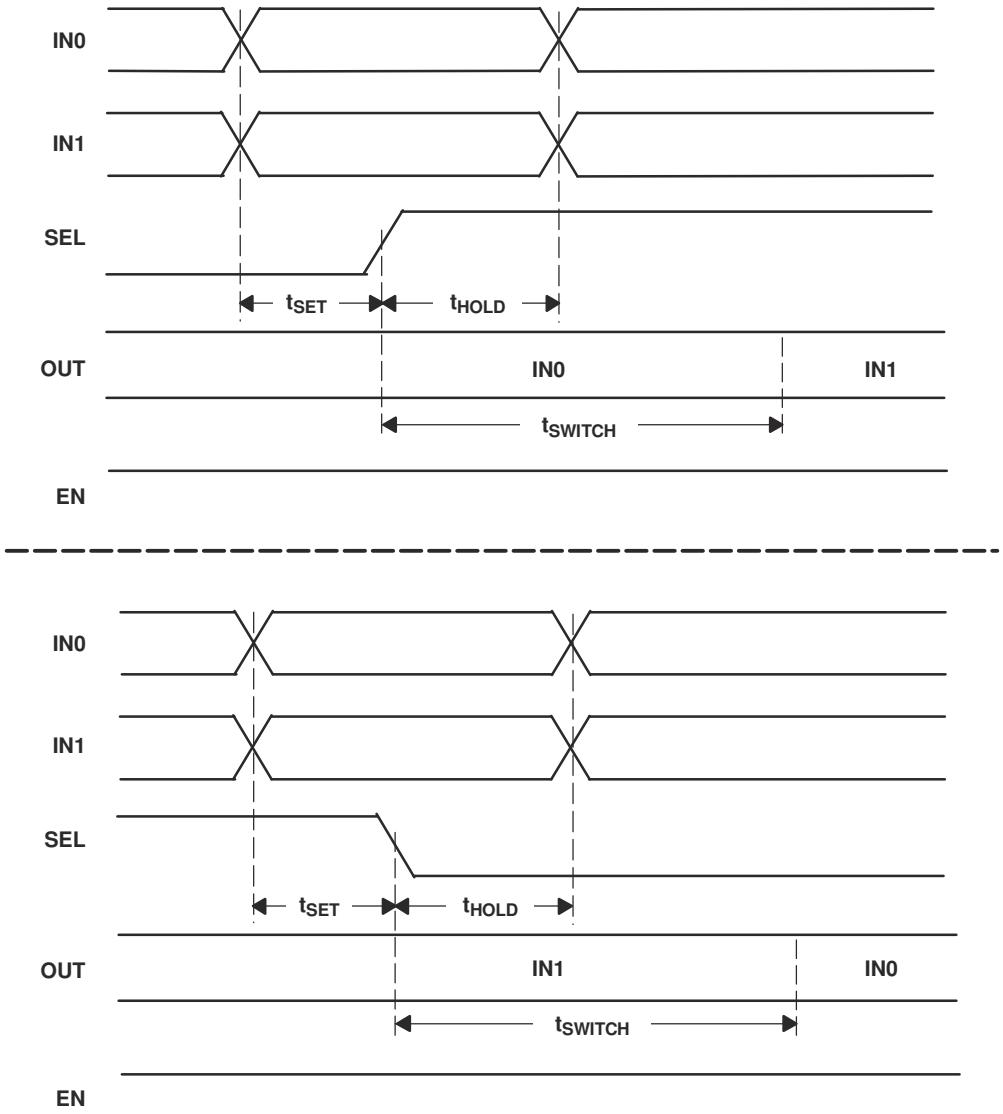
All input pulses are supplied by a generator having the following characteristics: t_r or t_f ≤ 1 ns, pulse-repetition rate (PRR) = 0.5 Mpps, pulse width = 500 ± 10 ns. C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.

Figure 7-6. Enable And Disable Time Circuit And Definitions

Table 7-1. Receiver Input Voltage Threshold Test

APPLIED VOLTAGES		RESULTING DIFFERENTIAL INPUT VOLTAGE	RESULTING COMMON-MODE INPUT VOLTAGE	OUTPUT(1)
V_{IA}	V_{IB}	V_{ID}	V_{IC}	
1.25 V	1.15 V	100 mV	1.2 V	H
1.15 V	1.25 V	–100 mV	1.2 V	L
4.0 V	3.9 V	100 mV	3.95 V	H
3.9 V	4. 0 V	–100 mV	3.95 V	L
0.1 V	0.0 V	100 mV	0.05 V	H
0.0 V	0.1 V	–100 mV	0.05 V	L
1.7 V	0.7 V	1000 mV	1.2 V	H
0.7 V	1.7 V	–1000 mV	1.2 V	L
4.0 V	3.0 V	1000 mV	3.5 V	H
3.0 V	4.0 V	–1000 mV	3.5 V	L
1.0 V	0.0 V	1000 mV	0.5 V	H
0.0 V	1.0 V	–1000 mV	0.5 V	L

(1) H = high level, L = low level



t_{SET} and t_{HOLD} times specify that data must be in a stable state before and after mux control switches.

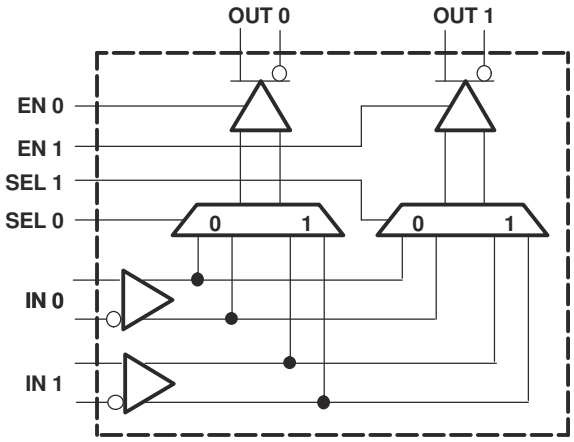
Figure 7-7. Input To Select For Both Rising And Falling Edge Setup And Hold Times

8 Detailed Description

8.1 Overview

The SN55LVCP22 is a high-speed 1-Gbps 2x2 LVDS redriving cross-point switch that can be used in mux or demux or splitter configurations. The SN55LVCP22 provides multiple signal switching options that allow system implementation flexibility as described in Table 8-1. The SN55LVCP22 incorporates wide common-mode (0 V to 4 V) receivers, allowing for the receipt of LVDS, LVPECL, and CML signals and low-power LVDS drivers to provide high-speed operations. The SN55LVCP22 uses a fully differential data path to ensure low-noise generation, fast switching times, low pulse width distortion, and low jitter.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Input Select Pins

SEL0 pin selects which differential input lane will be routed to Lane 0 driver differential output OUT0 and SEL1 pin selects which differential input lane will be routed to Lane 1 driver differential output OUT1

8.3.2 Output Enable Pins

EN0 pin is an active high enable for OUT0 driver differential output and EN1 pin is an active high enable for OUT1 driver differential output.

8.4 Device Functional Modes

Table 8-1. Function Table

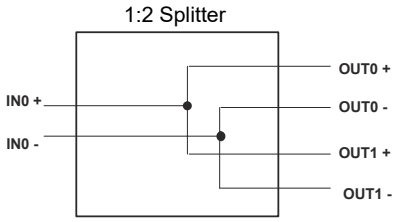
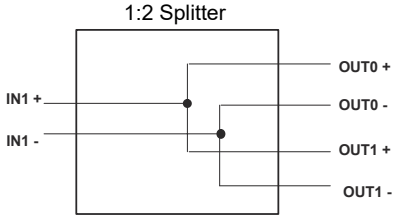
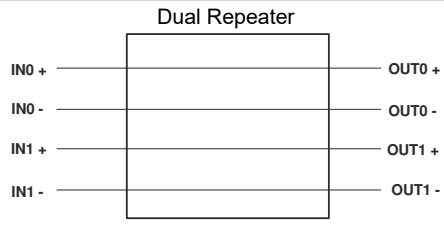
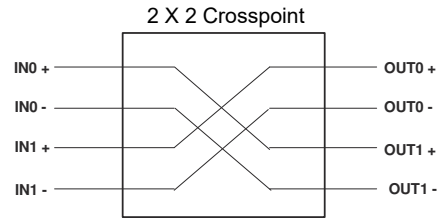
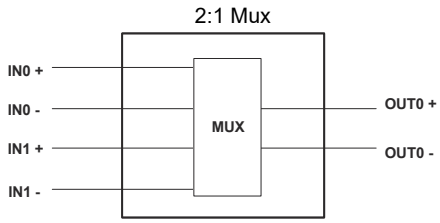
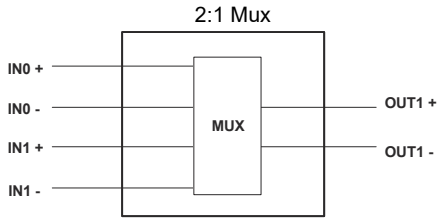
SEL0	SEL1	EN0	EN1	OUT0	OUT1	FUNCTION	SIGNAL FLOW
0	0	1	1	IN0	IN0	1:2 Splitter Input IN0	
1	1	1	1	IN1	IN1	1:2 Splitter Input IN1	

Table 8-1. Function Table (continued)

SEL0	SEL1	EN0	EN1	OUT0	OUT1	FUNCTION	SIGNAL FLOW
0	1	1	1	IN0	IN1	2-lane Repeater	
1	0	1	1	IN1	IN0	Cross-switch	
0	X	1	0	IN0	High-Z	2:1 Mux Output OUT0	
1				IN1			
X	0	0	1	High-Z	IN0	2:1 Mux Output OUT1	
	1				IN1		

9 Application and Implementation

9.1 Application Information

The SN55LVCP22 can support different kind of signaling at the receiver with proper termination network. The output drivers will output LVDS differential signals.

9.2 Typical Application

9.2.1 Low-Voltage Positive Emitter-Coupled Logic (LVPECL)

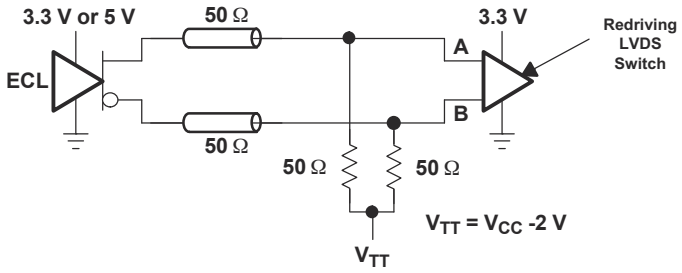


Figure 9-1. Low-Voltage Positive Emitter-Coupled Logic (LVPECL)

9.2.1.1 Design Requirements

Table 9-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Single-ended termination	50 Ω
V_{TT} termination voltage	V_{CC} -2 V

9.2.1.2 Detailed Design Procedure

Use two 50 Ω termination resistors (as close to the input pins as possible) with termination voltage of V_{TT} as described in Figure 9-1 to receive LVPECL input signals.

9.2.2 Current-Mode Logic (CML)

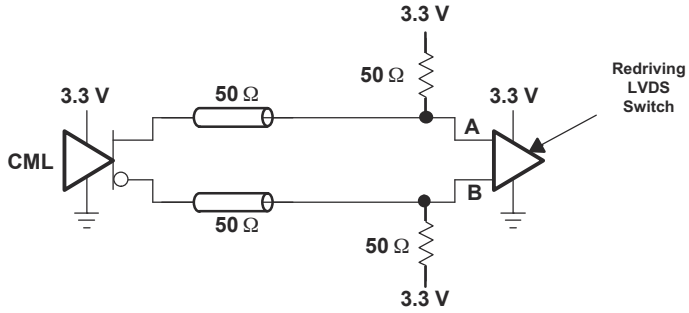


Figure 9-2. Current-Mode Logic (CML)

9.2.2.1 Design Requirements

Table 9-2. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Single-ended termination	50 Ω
Termination Voltage	V_{CC} = 3.3V

9.2.2.2 Detailed Design Procedure

Use two 50 Ω termination resistors (as close to the input pin as possible) with termination voltage of V_{CC} as described in Figure 9-2 to receive CML input signals.

9.2.3 Single-Ended (LVPECL)

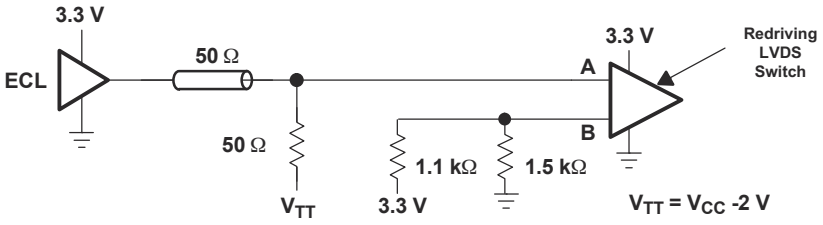


Figure 9-3. Single-Ended (LVPECL)

9.2.3.1 Design Requirements

Table 9-3. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Single-ended termination for input used	50 Ω
V_{TT} termination voltage	V_{CC} - 2 V
Unused input pull-up termination to V_{CC}	1.1 kΩ
Unused input pull-down termination to Gound	1.5 kΩ

9.2.3.2 Detailed Design Procedure

Use a 50 Ω termination resistor (as close to the input pin as possible) with termination voltage of V_{TT} as described in Figure 9-3 to receive Single-ended LVPECL input signals. Terminate Unused input pin with 1.1 kΩ pull-up to V_{CC} and 1.5 kΩ pull-down to ground.

9.2.4 Low-Voltage Differential Signaling (LVDS)

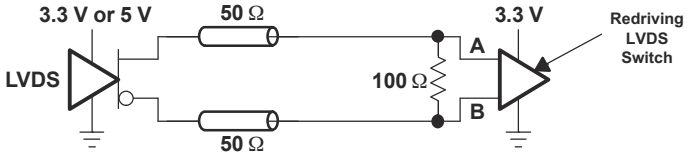


Figure 9-4. Low-Voltage Differential Signaling (LVDS)

9.2.4.1 Design Requirements

Table 9-4. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Differential Termination	100 Ω

9.2.4.2 Detailed Design Procedure

Use a 100 Ω differential termination resistor (as close to the input pins as possible) as described in Figure 9-4 to receive LVDS input signals.

9.2.5 Application Curves

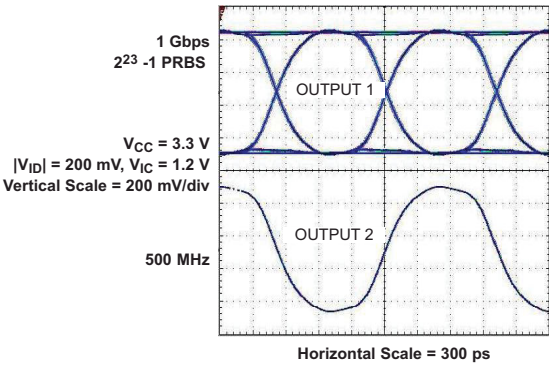


Figure 9-5. LVDS Output

10 Power Supply Recommendations

There is no power supply sequence required for SN55LVCP22. It is recommended that at least a 0.1uF decoupling capacitor is placed at the device VCC near the pin.

11 Layout

11.1 Layout Guidelines

High performance layout practices are paramount for board layout for high speed signals to ensure good signal integrity. Even minor imperfection can cause impedance mismatch resulting reflection. Special care is warranted for traces, connections to device, and connectors.

11.2 Layout Example

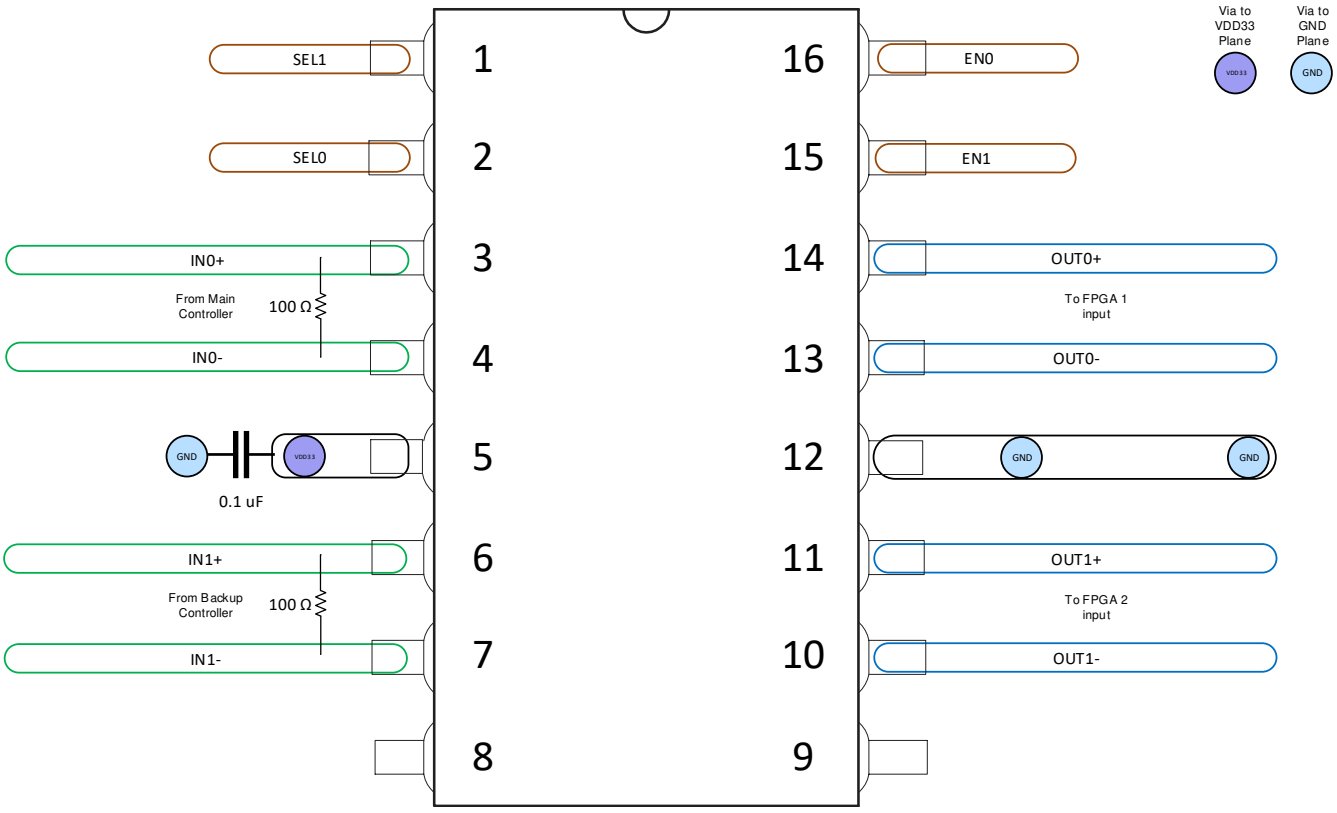


Figure 11-1. Layout Example with LVDS input signals

12 Device and Documentation Support

12.1 Trademarks

All other trademarks are the property of their respective owners.

12.2 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.3 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-1124201QFA	Active	Production	CFP (W) | 16	25 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-1124201QF A LVCP22W-SP

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

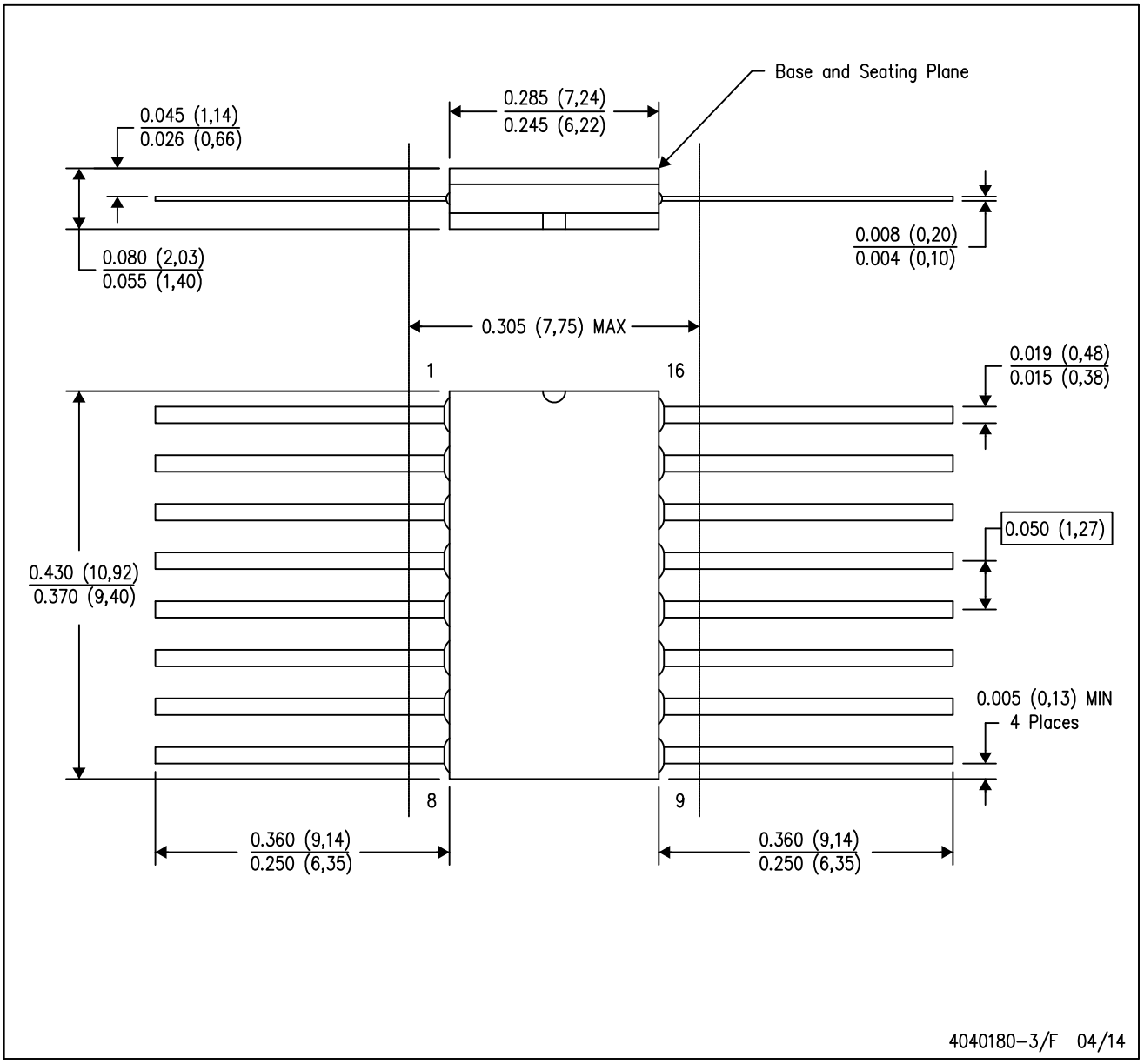
OTHER QUALIFIED VERSIONS OF SN55LVCP22 :

- Space : SN55LVCP22-SP

NOTE: Qualified Version Definitions:

- Space - Radiation tolerant, ceramic packaging and qualified for use in Space-based application

W (R–GDFP–F16) CERAMIC DUAL FLATPACK



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package can be hermetically sealed with a ceramic lid using glass frit.
D. Index point is provided on cap for terminal identification only.
E. Falls within MIL STD 1835 GDFP2–F16

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Last updated 10/2025